Total No. of Qu	estions : 4]	SEAT No. :
P5435		[Total No. of Pages : 1
[6186] 563		
S.E. (Automobile & Mechanical) (Mechanical Sandwich)		
(Automation & Robotics) (Insem)		
ENGINEERING MATERIALS AND METALLURGY		
(2019 Pattern) (Semester-III) (202044)		
Time: 1 Hour]		[Max. Marks : 30
Instructions to a 1) Attem	the candidates: pt Q.1 or Q.2, Q.3 or Q.4.	
	diagrams must be drawn wherever necessary.	
3) Figur	es to the right indicate full marks.	200
	ne suitable data, if Necessary. f electronic pocket calculator is allowed.	
3) Use of	j electionic pocket culculator is allowed.	Cold
Q1) a) Dra	withe following planes in cubic crystal sy	stem [6]
i), 🔯	(101)	
(Si)	(100)	~
iii)	$(111) \qquad \qquad \bigcirc$	•
b) Calo	culate planar atomic density of SC BCC a	and FCC on (100) Plane.[9]
(12) a) Con	OR OR	[7]
~ /	npare between ductile and brittle fracture.	
ŕ	at is cold working? Why Annealing is replain recovery, recrystallization and grain	
_	cess.	r growth during anneaning 18]
pro	ccss.	Zotol.
Q3) a) Def	ine formability. Draw Erichsen Cupping	test diagram What do you
	on by 'Radial' and 'Circumferential' crack	
	at do you mean by non-destructive testing	
	lain ultrasonic method of testing.	[9]
Z.i.p	OR /	
04) a) Con	npare between scanning and transmission	on electron microscopy on
	basis of following points: block diagram	
	process, magnification, use & disadvant	
_	plain how microscopic and macroscopic	
	estigating failure analysis in metals. Explai	
1111	Songaring fairers analysis in mounts. Explain	n spain tost in domin. [0]
	×,	